Type: Standard (20 min including discussion)

## **Status of 3D Detectors TCAD Simulations**

Wednesday 24 June 2015 11:20 (20 minutes)

We will present our results with TCAD Simulations of three different 3D Devices (ROC4Sense, Fermilab, PSI46). We have I-V, C-V and MIP simulations before and after irradiation up to  $2e15 n_eq/cm2$ . Also include will be a glimpse of our present effort for LGAD device simulations on MIP hit.

## **Summary**

TCAD Simulations (IV, CV, MIP, Irradiated (IV, CV, MIP)) of 3D Detectors

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Session Classification: Simulations